

SGLS415A-OCTOBER 2013-REVISED OCTOBER 2013

QUADRUPLE LOW-POWER DIFFERENTIAL RECEIVER

Check for Samples: SN55LBC173-HIREL

FEATURES

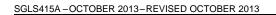
- Meets EIA Standards RS-422-A, RS-423-A, RS-485, and CCITT V.11
- Designed to Operate With Pulse Durations as Short as 20 ns
- Designed for Multipoint Bus Transmission on Long Bus Lines in Noisy Environments
- Input Sensitivity: ±200 mV
- Low-Power Consumption: 20 mA (Max)
- Open-Circuit Fail-Safe Design

DESCRIPTION

The SN55LBC173 is a monolithic quadruple differential line receiver with 3-state outputs designed to meet the requirements of the EIA standards RS-422-A, RS-423-A, RS-485, and CCITT V.11. This device is optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. The four receivers share two ORed enable inputs, one active when high, the other active when low. Each receiver features high input impedance, input hysteresis for increased noise immunity, and input sensitivity of ±200 mV over a common-mode input voltage range of 12 V to −7 V. Fail-safe design ensures that if the inputs are open circuited, the output is always high. The SN55LBC173 is designed using the Texas Instruments proprietary LinBiCMOS[™] technology that provides low power consumption, high switching speeds, and robustness.

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SN55LBC173-HIREL





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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

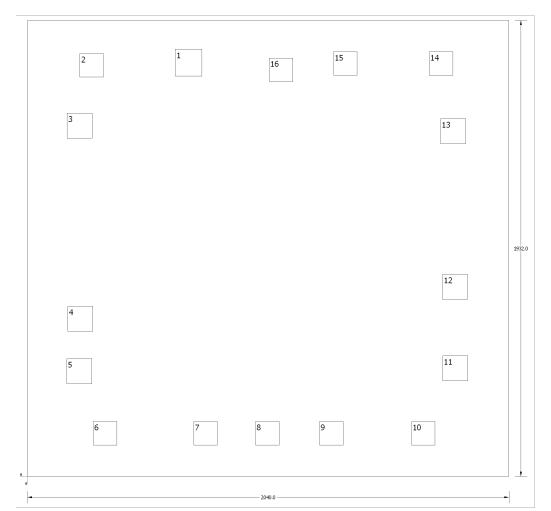
ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
55%C to 125%C	KCD	SN55LBC173MKGD1	NA
–55°C to 125°C	KGD	SN55LBC173MKGD2	NA

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

BARE DIE INFORMATION

DIE THICKNESS	BACKSIDE FINISH	BACKSIDE POTENTIAL	BOND PAD METALLIZATION COMPOSITION	BOND PAD THICKNESS
10.5 mils.	Silicon with backgrind	Floating	AlSi(1%)Cu(0.5%)TiW	1850 nm





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Table 1. Bond Pad Coordinates in Microns PAD NUMBER DESCRIPTION X MIN Y MIN X MAX Y MAX 1B 1 626.5 1695 740.5 1809.5 2 1A 222.5 1690.7 323 1791.3 1Y 3 167.9 1432.1 274.8 1539 G 4 171.4 614.1 278.3 721 2Y 5 166.6 392.1 273.5 499 2A 6 279.2 132 379.7 232.6 2B 7 704.8 132 805.3 232.6 GND 8 966.2 132 1066.7 232.6 3B 9 1237.2 132 1337.7 232.6 ЗA 10 1626.7 132 1727.2 232.6 3Y 11 1758.7 403.7 1865.6 510.6 G 12 1758.5 749 1865.4 855.9 4Y 13 1750.1 1408.4 1857 1515.3 4A 14 1702.2 1698.4 1802.7 1799 4B 15 1296.7 1698.4 1397.2 1799 VCC 16 1024.2 1671.9 1124.7 1772.5

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range unless otherwise noted

		Value	UNIT
V_{CC}	Supply voltage range ⁽²⁾	–0.3 to 7	V
VI	Input voltage range, (A or B inputs)	±25	V
V_{ID}	Differential input voltage ⁽³⁾	±25	V
	Data and control voltage range	–0.3 to 7	V
T _A	Operating free-air temperature range	-55 to 125	°C
T _{stg}	Storage temperature range	-65 to 150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.

RECOMMENDED OPERATING CONDITIONS

			MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage	4.75	5	5.25		
VIC	Common-mode input voltage		-7		12	
VIH	High-level input voltage	Q institu	2			V
VIL	Low-level input voltage	G inputs			0.8	
V_{ID}	Differential input voltage	-6		6		
I _{OH}	High-level output current				-8	mA
I _{OL}	Low-level output current				16	mA
T _A	Operating free-air temperature	Dperating free-air temperature				°C

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ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAM	ETER	TEST C	ONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going inp	out threshold voltage	I _O = -8 mA	$I_{O} = -8 \text{ mA}$			0.2	
V _{IT}	Negative-going ir	put threshold voltage	I _O = 8 mA		-0.2			V
V _{hys}	Hysteresis voltag	e (V _{IT+} – V _{IT–})				45		mV
VIK	Enable input clan	np voltage	I _I = – 18 mA			-0.9	-1.5	V
V _{OH}	High-level output	voltage	$V_{ID} = -200 \text{ mV}, I_{OH} = -8$	mA	3.5	4.5		V
V			$V_{ID} = -200 \text{ mV}, I_{OL} = 8 \text{ mA}$			0.3	0.5	V
V _{OL}	Low-level output voltage		$V_{ID} = -200 \text{ mV}, I_{OL} = 8 \text{ mA}, T_A = 125^{\circ}$				0.7	V
l _{oz}	High-impedance-	state output current	$V_{O} = 0 V \text{ to } V_{CC}$				±20	μA
		· A OF B INDUIS	V _{IH} = 12 V, V _{CC} = 5 V	Other inputs at 0 V		0.7	1.15	
	Bus input		V _{IH} = 12 V, V _{CC} = 0 V			0.8	1.15	mA
IJ	current		$V_{IH} = -7 V, V_{CC} = 5 V$			-0.5	-0.9	
			$V_{IH} = -7 V, V_{CC} = 0 V$			-0.4	-0.9	
I _{IH}	High-level input current		V _{IH} = 5 V				±20	μA
I _{IL}	Low-level input current		$V_{IL} = 0 V$				-20	μA
l _{os}	Short-circuit output current		$V_0 = 0$			-80	-120	mA
	Supply ourrest		Outputs enabled, $I_0 = 0$, $V_{ID} = 5 V$			11	20	~
I _{CC}	Supply current		Outputs disabled			0.9	1.4	mA

(1) All typical values are at 25°C and with a 5 V supply.

SWITCHING CHARACTERISTICS

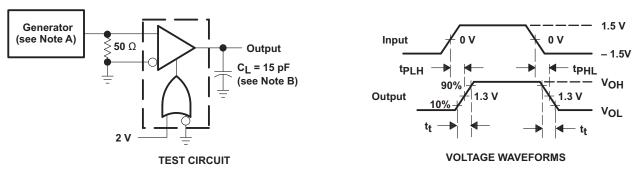
 V_{CC} = 5 V, C_{L} = 15 pF, over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT	
	Propagation delay time, high-to-low-level	$V_{ID} = -1.5 \text{ V}$ to 1.5 V,	25°C	11	22	30		
t _{PHL}	output	See Figure 1	–55°C to 125°C	11		35	ns	
	Propagation delay time, low-to-high-level	$V_{ID} = -1.5 \text{ V}$ to 1.5 V,	25°C	11	22	35		
t _{PLH}	output	See Figure 1	–55°C to 125°C	11		35	ns	
			25°C		17	40		
t _{PZH}	Output enable time to high level	See Figure 2	–55°C to 125°C			45	ns	
			25°C		18	30		
t _{PZL}	Output enable time to low level	See Figure 3	–55°C to 125°C			35	ns	
			25°C		30	40		
t _{PHZ}	Output disable time from high level	See Figure 2	–55°C to 125°C			55	ns	
	Output dischle time from low lovel	See Figure 2	25°C		25	40	20	
t _{PLZ}	Output disable time from low level	See Figure 3	–55°C to 125°C			45	ns	
			25°C		0.5	6		
t _{sk(p)} Pulse skew	Pulse skew (t _{PHL} – t _{PLH})	See Figure 1	–55°C to 125°C			7	ns	
			25°C		5	10		
t _t	Transition time	See Figure 1	–55°C to 125°C			16	ns	



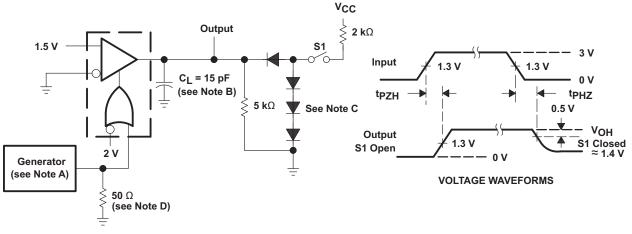
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PARAMETER MEASUREMENT INFORMATION



- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

Figure 1. t_{pd} and t_t Test Circuit and Voltage Waveforms

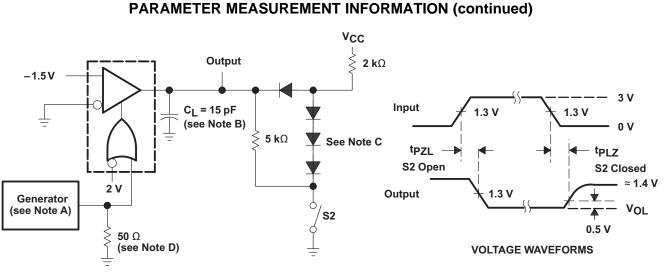


TEST CIRCUIT

- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.
- C. All diodes are 1N916 or equivalent.
- D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 2. t_{PHZ} and t_{PZH} Test Circuit and Voltage Waveforms

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TEST CIRCUIT

- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.
- C. All diodes are 1N916 or equivalent.
- D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 3. t_{PZL} and t_{PLZ} Test Circuit and Voltage Waveforms

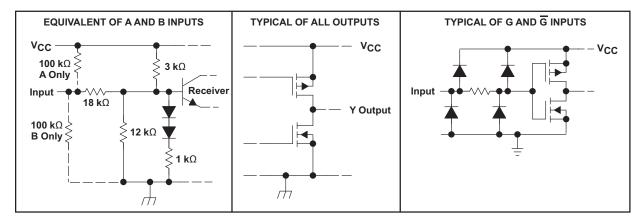
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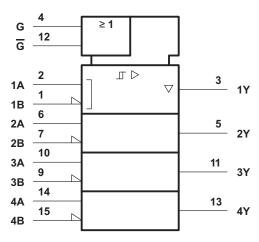
DEVICE INFORMATION

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



FUNCTION TABLE (EACH RECIEVER)

DIFFERENTIAL INPUTS	ENA	OUTPUT	
A - B	G	G	Y
	Н	Х	Н
V _{ID} ≥ 0.2 V	Х	L	Н
	Н	Х	?
-0.2 < V _{ID} < 0.2 V	Х	L	?
	Н	Х	L
$V_{ID} \le -0.2 V$	Х	L	L
Х	L	Н	Z
	Н	Х	Н
Open circuit	Х	L	Н





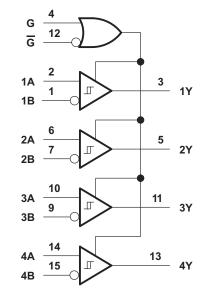
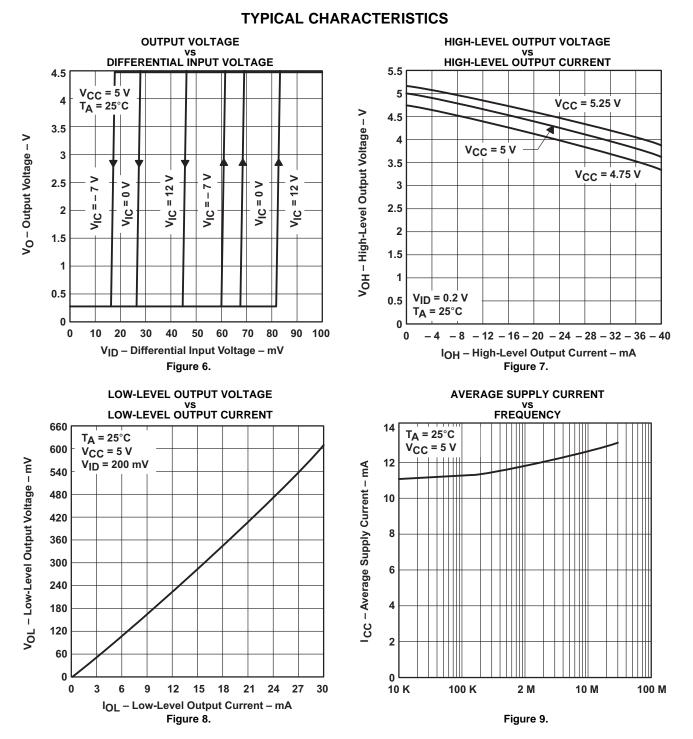


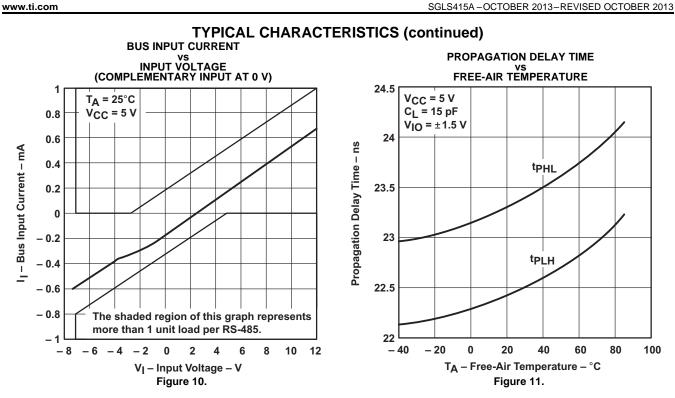
Figure 5. Logic Diagram (Positive Logic)



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN55LBC173MKGD1	ACTIVE	XCEPT	KGD	0	100	TBD	Call TI	N / A for Pkg Type	-55 to 125		Samples
SN55LBC173MKGD2	ACTIVE	XCEPT	KGD	0	10	TBD	Call TI	Call TI	-55 to 125		Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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